

SEMiSTART

Antiparallel thyristors for softstart

SKKQ 560

Features

- Compact design
- Thyristor with amplifying gate
- Pressure contact technology

Typical Applications*

- Soft Starters

Remarks

- Please note: This module has no soft mold protection around the chip. It is therefore susceptible to environmental influences (dust, humidity, etc.). The humidity test according to IEC60068-2-67 is not passed by this product.
- Recommendation: The devices should be installed in control cabinets of IP54 degree of protection.

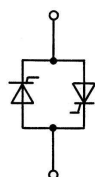
1) T_{vjmax} up to 150°C is allowable for overload conditions, max. time period for the overload condition is 20s.

Absolute Maximum Ratings

Symbol	Conditions	Values	Units
$I_{overload}$	W1C; sin. 180°; 20 sec.; $T_{vjmax} = 150\text{ °C}$; $T_{vjstart} = 40\text{ °C}$	560	A
I_{TSM}	$T_{vj} = 25\text{ °C}$; 10 ms	5700	A
	$T_{vj} = 125\text{ °C}$; 10 ms	5200	A
I^2t	$T_{vj} = 25\text{ °C}$; 8,3 ... 10 ms	162000	A ² s
	$T_{vj} = 125\text{ °C}$; 8,3 ... 10 ms	135000	A ² s
SKKQ 560/14			
V_{RSM}		1500	V
V_{RRM}, V_{DRM}		1400	V
SKKQ 560/18			
V_{RSM}		1900	V
V_{RRM}, V_{DRM}		1800	V
T_{vj}		-40 ... +125 ¹⁾	°C
T_{stg}		-40 ... +125	°C

Characteristics

Symbol	Conditions	min.	typ.	max.	Units
V_T	$T_{vj} = 25\text{ °C}$; $I_T = 1000\text{ A}$			1,9	V
$V_{T(TO)}$	$T_{vj} = 125\text{ °C}$			0,9	V
r_T	$T_{vj} = 125\text{ °C}$			0,9	mΩ
I_{DD}, I_{RD}	$T_{vj} = 125\text{ °C}$; $V_{RD} = V_{RRM}$; per module			80	mA
t_{gd}	$T_{vj} = 25\text{ °C}$; $I_G = 1\text{ A}$; $di_G/dt = 1\text{ A}/\mu\text{s}$		1		μs
t_{gr}	$V_D = 0,67 * V_{DRM}$		2		μs
$(dv/dt)_{cr}$	$T_{vj} = 125\text{ °C}$		1000		V/μs
$(di/dt)_{cr}$	$T_{vj} = 125\text{ °C}$; $f = 50 \dots 60\text{ Hz}$		125		A/μs
t_q	$T_{vj} = 125\text{ °C}$		150		μs
I_H	$T_{vj} = 25\text{ °C}$		150	400	mA
I_L	$T_{vj} = 25\text{ °C}$; $R_G = 33\text{ Ω}$		300	1000	mA
V_{GT}	$T_{vj} = 25\text{ °C}$; d.c.	2			V
I_{GT}	$T_{vj} = 25\text{ °C}$; d.c.	150			mA
V_{GD}	$T_{vj} = 125\text{ °C}$; d.c.			0,25	V
I_{GD}	$T_{vj} = 125\text{ °C}$; d.c.			10	mA
$R_{th(j-s)}$	cont.; per thyristor			0,106	K/W
M_t			5 ± 15%		Nm
m			530		g
Case			C 11		



W1C

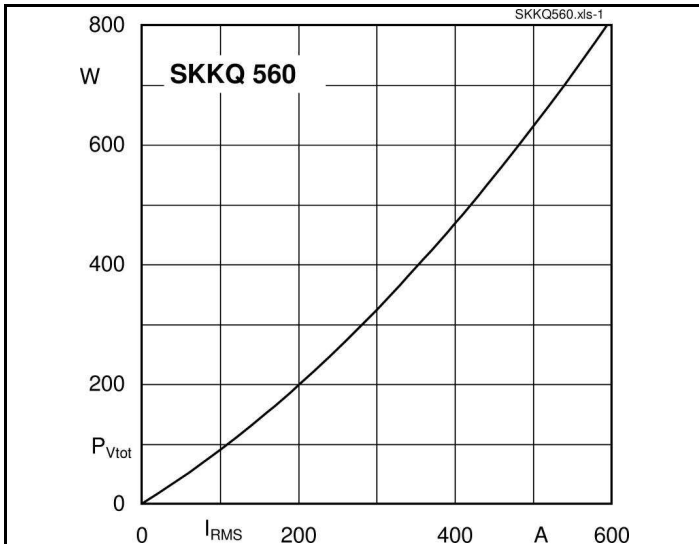


Fig. 1 Power dissipation per module vs. rms current

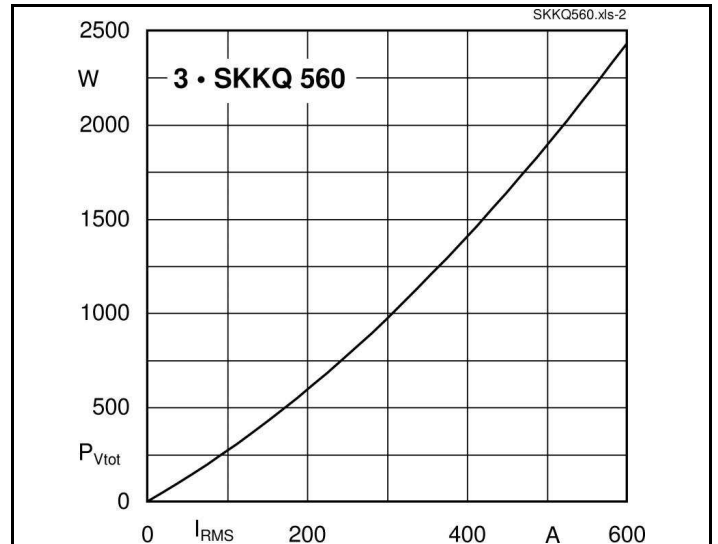


Fig. 2 Power dissipation of three modules vs. rms current

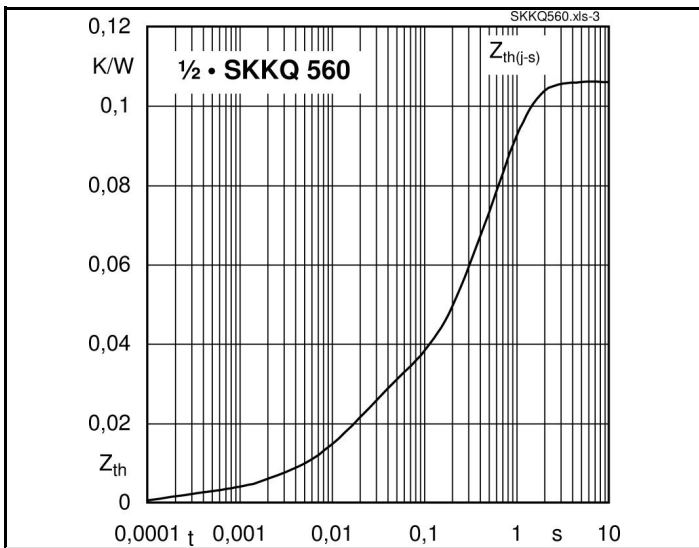


Fig. 3 Transient thermal impedance $Z_{th(j-s)}$ vs. time

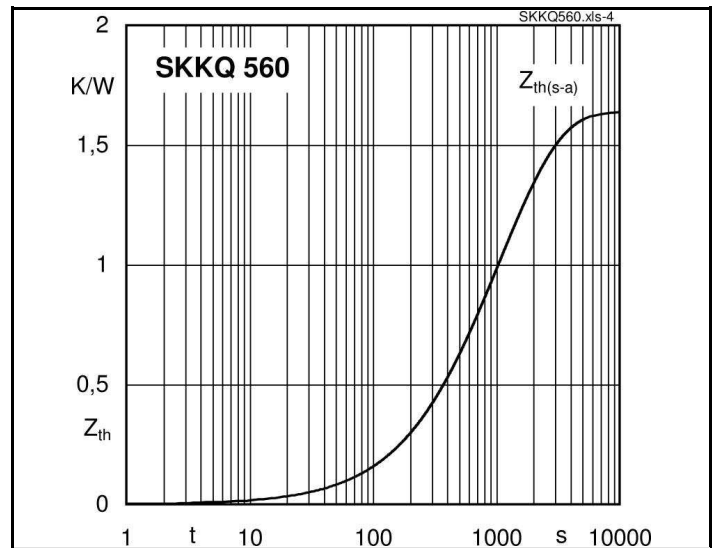


Fig. 4 Typ. transient thermal impedance $Z_{th(s-a)}$ vs. time (natural cooling)

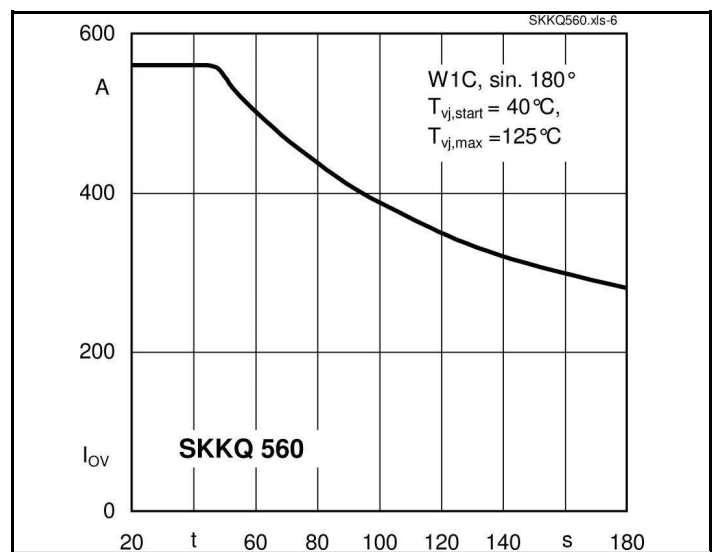
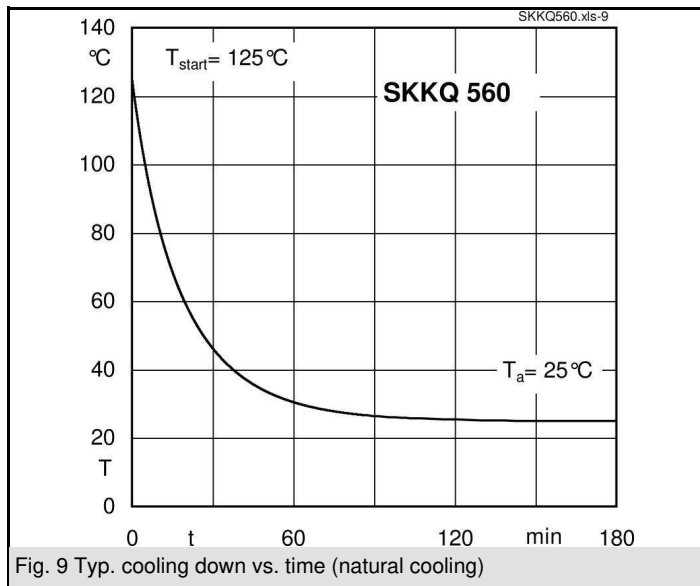
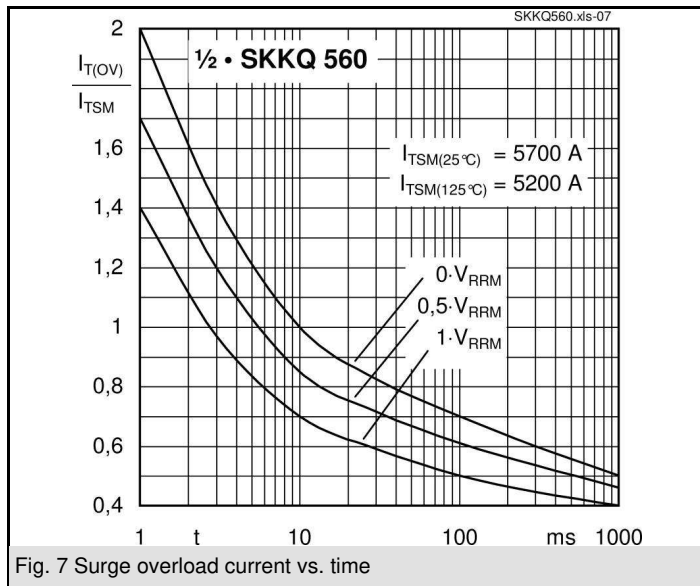
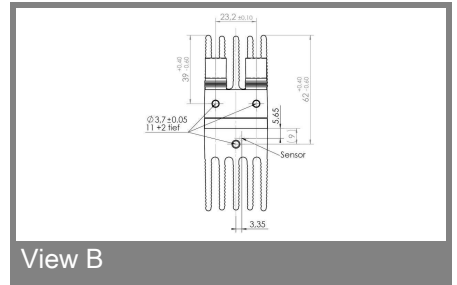
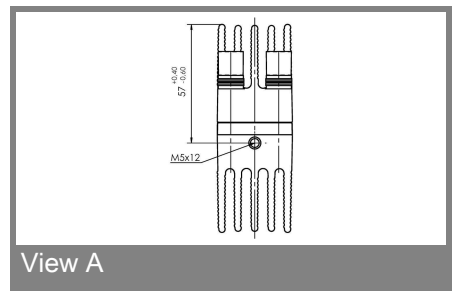
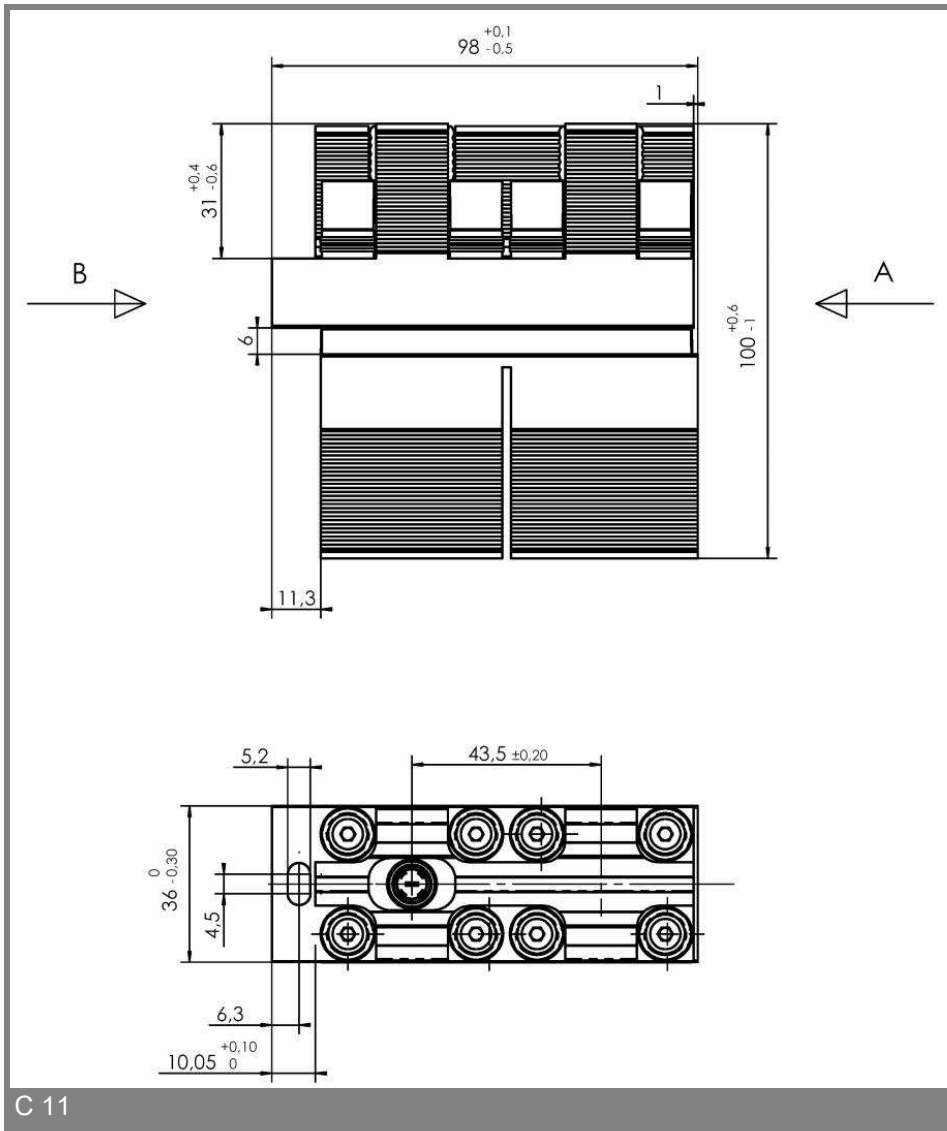


Fig. 6 Typ. overload current vs. time (natural cooling)





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* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.